



European Materials Research Society

# 2026 Spring Meeting

May 25 - 29  
Strasbourg Convention Centre

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## SYMPOSIUM 5

Material-related problems of neuromorphic technologies

Oral sessions : **ROME - GROUND FLOOR**

Poster sessions : **ETOILE - FIRST FLOOR**

*Symposium Organizers:*

**Hans CHO**, US Naval Research Laboratory (NRL), USA

**Marina SPARVOLI**, Universidade Federal do ABC (UFABC), Brazil

**Nikolai A. SOBOLEV** (Main organizer), Universidade de Aveiro, Portugal

**Ronald TETZLAFF**, Technische Universität Dresden, Germany

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Monday May 25  
**S01 Switching Mechanisms**

Chairperson(s): SOBOLEV Nikolai a.

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08:30	2672	Diffusive valence change memory: nanoionic mechanisms and prospects for neuro-inspired computing <b>HELLWIG Johannes (Invited)</b>
09:00	789	Influence of thickness on the electrical and physical properties of Ge-rich GST layers used to engineer PCM <b>DIAKHATE Birame</b>
09:15	3153	Short-Term Synaptic Plasticity in TaOx-based VCM Devices at Sub-nanosecond Timescales <b>MUNIR Faisal</b>
09:30	3005	Material properties-driven analysis of the filament formation in oxygen-engineered yttria-based resistive memories <b>DUAN Yu</b>
09:45	1726	Electronic Pain Perception: CeO2-Based Diffusive Memristors for Olfactory Nociception <b>KUZHIMBATTIL Bhagyalakshmi</b>

Monday May 25  
**S02 Networks**

Chairperson(s): HERON John

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10:30	51	Material Aspects of Resistive Switching in Nanogranular Matter <b>VAHL Alexander (Invited)</b>
11:00	2648	Reservoir computing with organic mixed ionic electronic conductors <b>KANTELBERG Richard</b>
11:15	1604	Aqueous Proton-Driven Reservoir Computing Using a Graphene Chemimemristor <b>TANG Senlin</b>
11:30	268	On-Chip Analog Signal Processing using MoS2 based Reservoir Computer <b>WEN Yingyi</b>
11:45	960	Retina-Inspired 2D Semiconductor NIR Sensor with PRO Architecture <b>XU Jian-Bin</b>

Monday May 25  
**S03 Memristors**

Chairperson(s): VAHL Alexander

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14:30	2532	Switching Dynamics in Memristors <b>SPAGNOLO Bernardo (Invited)</b>
15:00	3166	Benchmarking stochasticity behind reproducibility: full cycle noise measurements and denoising strategies in memristive devices <b>HALBRITTER András Erno (Invited)</b>
15:30	1132	Threshold Switching Memristor-Based Capacitively Coupled Oscillators for Mixed Weight Modulation <b>CHEN Chi-Chien</b>
15:45	2700	Development of a tabletop AFM system for spatially resolved conductive noise measurement on memristive samples <b>FEHERVARI János Gergo</b>

Monday May 25  
**S04 Switching Dynamics**

Chairperson(s): CSONTOS Miklós

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16:30	117	Temporal correlation effects in memristive devices on the sub-ns scale <b>Menzel Stephan (Invited)</b>
17:00	3009	Reconfigurable Multistate Optical Memory in Mixed Halide Perovskites <b>KOUWENHOVEN Marcel</b>
17:15	2966	VO2 oscillators and artificial neurons optimized for ultrafast operation <b>POLLNER Zsigmond</b>
17:30	2475	From short- to long-term stability in VCM based RRAM <b>WIEFELS Stefan (Invited)</b>
18:00	1330	An Elemental Phase-Change Memory Based on Germanium <b>ZELLWEGER Till</b>
18:15	1090	Material-Dependent Sneak-Path Effects and Scalability Limits in Neuromorphic Crossbar Arrays <b>LIM Donghyeok</b>

**Tuesday May 26**  
**S05 Organic Devices**  
 Chairperson(s): RACKAUSKAS Simas

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08:30	2198	Critical charge transport networks in doped organic semiconductors <b>HOFACKER Andreas (Invited)</b>
09:00	2747	Using UV light to shift the Threshold Voltage in Organic Electrochemical Transistors <b>TEUERLE Laura</b>
09:15	2549	Memory Level Rewriting in Fiber-like Vertical Organic Electrochemical Transistors for Neuromorphic Applications <b>F. P. BARBOSA Henrique</b>
09:30	1425	Investigating Ion–Electron Coupling in n-Type Organic Mixed Ionic–Electronic Conductors through Device Architecture and Electrolyte Engineering <b>KIM Hye-Jung</b>
09:45	988	An Organic–Inorganic Y7C/SiO <sub>2</sub> Heterojunction Memristor with Highly Uniform Switching and Multilevel resistance States <b>PARK Kyung Jun</b>

**Tuesday May 26**  
**S06 Neuromorphic computing**  
 Chairperson(s): HOFACKER Andreas

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10:30	3414	Reconfigurable Nonlinear Computing in Silicon <b>VAN DER WIEL Wilfred G. (Invited)</b>
11:00	3365	Liquid state memristors for in-memory and neuromorphic computing <b>PERSHIN Yuriy (Invited)</b>
11:30	3277	Probabilistic computing with organic electronics <b>CALVET Laurie (Invited)</b>

**Tuesday May 26**  
**S07 Vanadium oxide and related materials**  
 Chairperson(s): VAN DER WIEL Wilfred g.

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13:45	2748	Neuromorphic memristive sensors based on vanadium dioxide <b>IONESCU AM Adrian (Invited)</b>
14:15	3203	Toward GHz operation of oscillating neural networks <b>CSONTOS Miklós</b>
14:30	3244	From Piezoelectric MEMS Signals to Neuromorphic Encoding Using Memristive Materials <b>VOLK János</b>

14:45	1112	Biologically Plausible Neuron Circuit Realizing Intrinsic Neuronal Plasticity and Spiking Pattern Modulation via Dual-Mode Mott Memristor <b>HSU Kai-Shin</b>
15:00	1297	Electrical Characterization of Sheet and Contact Resistances of VO <sub>2</sub> Transmission Line Model (TLM) Structures with Ti/Au Electrodes <b>ZENG Xi</b>
15:15	726	Tuning of resistive-switching properties of VO <sub>2</sub> <b>AMBROSI JALÓN David</b>
15:30	3417	Optoelectronic Reservoir Computing: Advancing Next-Generation Neuromorphic Hardware <b>DIAS Lilia M. S.</b>
15:45	1079	Optimization of sputtered -MoO <sub>3</sub> thin films for memristor application <b>TYAGI Ayushi</b>

**Tuesday May 26**  
**S08 Ferroelectric Devices and Photomemristors**  
 Chairperson(s): IONESCU Mihai adrian

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16:30	2634	Picosecond ferroelectric dynamics, circuit-aware scaling, and charge-domain in-memory computing <b>HERON John (Invited)</b>
17:00	3175	Hf <sub>0.5</sub> Zr <sub>0.5</sub> O <sub>2</sub> /GaO <sub>x</sub> Ferroelectric Tunnel Junction with tunable GaO <sub>x</sub> conductivity <b>DUTTA Mrinmoy</b>
17:15	1685	Photomemristors for neuromorphic vision <b>TAN Hongwei</b>
17:30	1320	Ferroelectric properties of interface engineered HZO multilayers <b>MOHANDAS MOOLAYIL Sajmohan</b>
17:45	882	Automated Training and Neuromorphic Performance of Ferroelectric Crossbar Arrays Based on PZT and BTO Heterostructures on Silicon and STO <b>RENGIFO Miguel</b>
18:00	3120	Multilevel Resistance States Induced by Polarization Switching in Epitaxial Ferroelectric HfO <sub>2</sub> Films <b>FINA Ignasi</b>

**Wednesday May 27**  
**S09 Theory and Modeling**

Chairperson(s): CHO Hans

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08:30	2830	High-Order Ising Machines and Hopfield Neural Networks for Combinatorial Optimization <b>STRUKOV Dmitri (Invited)</b>
09:00	1296	Simulating Electro-Thermal Resistive Switching Dynamics in Strongly Correlated Thin-Film Devices for Neuromorphic Computing <b>GUÉNON Stefan</b>
09:15	1329	Mechanisms of creation of oxygen vacancies in amorphous Ga <sub>2</sub> O <sub>3</sub> and Ta <sub>2</sub> O <sub>5</sub> films <b>SHLUGER Alexander</b>
09:30	3396	Oxygen scavenging at a SiO <sub>2</sub> /Ta interface: a first-principles study <b>BURASCHI Margherita</b>
09:45	2154	Microscopic Origin of Dopant-Induced Destabilization of the Monoclinic Insulating Phase in Vanadium Dioxide: A DFT+U Study <b>TRIPATHI Shivam</b>

**Wednesday May 27**  
**S10 Unconventional Media I**

Chairperson(s): STRUKOV Dmitri

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10:30	810	Spray-Coated ZnO Tetrapod Networks as a Reproducible Platform for Neuromorphic Computing <b>RACKAUSKAS Simas (Invited)</b>
11:00	2834	BEOL-Compatible Wafer-Scale Two-Terminal Floating-Gate Memory for Neuromorphic Computing <b>NGUYEN Minh Chien</b>
11:15	1290	Morphological properties of metallic nanowire networks for reservoir computing <b>SCHUMACHER Sebastian</b>
11:30	42	Cluster-type conductive path-based selector-less 1R memristor array for spiking neural networks <b>YOON Jung Ho</b>
11:45	2552	Solution processed Zinc Oxide Optoelectronic Memristors for Neuromorphic Applications <b>PARREIRA Carolina</b>

**Wednesday May 27**  
**SPO3 Poster session 3**

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13:45	01_1008	Thermo-Optoelectronic Synaptic Device for Neuromorphic Applications <b>GHOSH Sirsendu</b>
13:45	02_1432	Optical control of the polarization states in 2D -In <sub>2</sub> Se <sub>3</sub> /hBN/Graphene FET <b>GHOSH Prasenjit</b>

13:45	03_1459	Light-Programmable Neuromorphic Hardware: Materials Strategies for Bidirectional Plasticity <b>MEI Tingting</b>
13:45	04_1887	Memristive and optoelectronic dynamics of 3D ZnO tetrapod networks <b>SOBOLEV Nikolai A.</b>
13:45	05_1898	Polarization-Driven Resistive Switching Memristor Based on a Semiconductor/Ferroelectric Heterostructure for Brain-Inspired Neuromorphic Computing <b>GHOSH Santu Kumar</b>
13:45	06_2045	Synthesis of Amorphous-Crystalline Mixture Boron Nitride for balanced Resistive Switching Operation <b>AGGARWAL Pallavi</b>
13:45	07_2731	Gallium oxide-based photomemristor for neural circuit emulation under optical stimulation <b>SPARVOLI Marina</b>
13:45	08_2772	Photomemristive Response of Thin TiO <sub>2</sub> Films: Role of Oxygen Partial Pressure in the Electronic and Optical Properties <b>SPARVOLI Marina</b>
13:45	09_2829	ZnO nano-tetrapod networks: scalable deposition and functionalization for neuromorphic technologies <b>RACKAUSKAS Simas</b>
13:45	10_2985	VerilogA Implementation of a Physics-Based NiO RRAM Model for Neuromorphic Circuits <b>SAHU Chopali Chanchal</b>
13:45	11_3126	Influence of oxygen flow rate and power on properties of HfO <sub>2</sub> thin films deposited by RF magnetron sputtering <b>ANAMIKA Anamika</b>
13:45	12_3311	Optoelectronics Synaptic TFTs for Neuromorphic Vision Sensors <b>LEONARDO Diogo</b>
13:45	13_3367	Innovative tourmaline-based photomemristors deposited by electron beam <b>SPARVOLI Marina</b>
13:45	14_3392	Substrate-Morphology-Driven Strain Engineering of Mott Insulators for Neuromorphic Device Materials <b>SINGH Reetendra</b>
13:45	15_3393	Planar vs. Nonplanar Porphyrin-SWNT Networks for Light-Enhanced In-Materio Physical Reservoir Computing <b>USAMI Yuki</b>
13:45	16_3395	Resistive Switching in Functional Oxides: Thickness, Defects, and Interfacial Effects <b>ABHIMANYU SINGH Rana</b>
13:45	17_3405	Investigating low-temperature crystalline layered MoO <sub>3</sub> films for memristor applications <b>TYAGI Ayushi</b>
13:45	18_3406	Investigation of Bottom Electrode Effects on Printed Hafnium Nanoparticle Memristors <b>LOHRKE Leonardo</b>
13:45	19_3412	In-Materio Encryption Using Nonlinear Ag NPs Devices and Reservoir Computing-Based Decryption <b>YAMASHITA Yuma</b>
13:45	20_3415	2D Memristor RF Switches for Scalable Reconfigurable Intelligent Surfaces at D-Band <b>MINGATES Tomás</b>

13:45	21_3416	Single-Atom Substitution in Keplerate Polyoxometalates for Reservoir-Dynamics Engineering in Physical Reservoir Computing <b>RAI Harshita</b>
13:45	22_605	Engineering High-Ionic-Mobility Interfaces to Expand Memristive Memory Windows <b>SAHU Debabrata</b>
13:45	23_737	Spray-Coated ZnO Tetrapod Networks as a Reproducible Platform for Neuromorphic Computing <b>GHOSHAL Sagarneel</b>
13:45	24_899	Optoelectronic Perovskite Synapses for Neuromorphic Computing and Reliability Analysis <b>GUPTA Govind</b>
13:45	25_943	An Organic-Inorganic Y7C/SiO2 Heterojunction Memristor with Highly Uniform Switching and Multilevel resistance States <b>ROY Abhishek</b>
13:45	26_983	Oxygen Defect State Modulation in Double-Layered ZnON/InGaZnO Photonic Synaptic Devices <b>LEE Yunsang</b>
13:45	27_1103	Oxygen Defect State Modulation in Double-Layered ZnON/InGaZnO Photonic Synaptic Devices <b>CHUNG Kwun-Bum</b>

**Thursday May 28**  
**S12 Heterostructures and thin films**

Chairperson(s): SPARVOLI Marina

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08:30	2619	Solid-State Redox as a Design Principle: Intertwining Heterostructure and Function in Complex Oxides for Neuromorphic Electronics <b>ESPOSITO Vincenzo (Invited)</b>
09:00	1727	Memristive Switching Characteristics of RF Magnetron Sputtered CeOx/SnOx Thin-Film Devices <b>KALRA Amanpreet</b>
09:15	2644	Printed ZTO resistive switching devices towards 1T1R Architectures <b>MARTINS Raquel</b>
09:30	604	Low-Voltage and Highly Stable Pt/TiO2/MoO3/MoN-Based Resistive Switching Memory for Synaptic Applications <b>KHAN Amir Sohail</b>
09:45	3197	Defect engineering of hafnium oxide for tailored device performance in resistive random-access memory (RRAM) devices <b>PIROS Eszter</b>

**Thursday May 28**  
**S13 Unconventional Media II**

Chairperson(s): MENZEL Stefan

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10:30	1709	Material intelligence: Material Physical Reservoir Devices for Highly Efficiency Intelligent Robot Systems <b>TANAKA Hirofumi (Invited)</b>
11:00	2763	Multicore memristor from electrically readable multiple domain walls in nanoscopic racetracks <b>JEON Jae-Chun</b>
11:15	1802	Material-Related Network Manipulations and Multiscale Functional Analysis of Neuromorphic Nanoparticle Networks via In Situ Electron Microscopy <b>GRONENBERG Ole</b>
11:30	3394	A Microfluidic Platform for Particle-Driven Dynamic Aqueous Reservoir Computing <b>XU Muzhen</b>
11:45	3408	Soft reconfigurable self-assembled materials for embodied computing <b>BORGHI Francesca</b>

**Thursday May 28**  
**S14 Reliability**

Chairperson(s): TANAKA Hirofumi

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13:45	1909	Materials requirements for the transition from digital to analog memristors <b>ALFF Lambert (Invited)</b>
14:15	2329	Revealing Conductive Filament Structure and Electrochemical Failure Mechanisms in MIEC Analog Memristors <b>KOROLEVA Aleksandra</b>
14:30	432	Engineering High-Ionic-Mobility Interfaces to Expand Memristive Memory Windows <b>JOSÉ COSTA Diogo</b>
14:45	2111	Multi-technique study of resistive switching mechanisms in Au-seeded CuO thin-film based memristors <b>OZGA Monika</b>
15:00	2450	Impact of La doping on the filament stability and noise characteristics of HfO2-based RRAM revealed through a comparative study <b>LI Yingxin</b>
15:15	2986	Non-volatile oxygen-vacancy-driven synapse devices using solution-processed NiO devices <b>ROY Abhrajit</b>
15:30	1786	Ionic Relaxation and Temperature Effects in Multilevel Memristors for Reliable Neuromorphic Functionality <b>VARELA-DOMÍNGUEZ Noa</b>
15:45	3407	Printed High-Entropy Metal-Organic Framework (HE-MOF) Memristors <b>LIU Yan</b>

Thursday May 28  
**S15 2D Memristor Devices**  
Chairperson(s): SOBOLEV Nikolai a.

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16:30	87	Resistive switching in 2D MXenes: from fundamental studies to neuromorphic properties <b>VENTURA Joao (Invited)</b>
17:00	58	Ultra-thin memristors based on 2D inorganic and metal-organic frameworks for neuromorphic computing <b>MILICHKO Valentin</b>
17:15	2313	MoS <sub>2</sub> Nanogap Memristive Devices for Artificial Synapses and Temporal Pattern Recognition <b>SATHEESH BABU Roshni</b>
17:30	2258	Engineered growth of MoxW <sub>1-x</sub> S <sub>2</sub> nanofilms for memristive switching applications <b>JANGRA Vikas</b>
17:45	2807	Addressing Material Challenges in TMD-based Memristive Devices <b>VEERALINGAM Sushmitha</b>
18:00	1950	Multifunctional Graphene Circuit Enabling Compact and Variability-Resilient Hardware Neural Network <b>UDAYA MOHANAN Kannan</b>
18:15	844	Brain-Inspired Plasticity and Cognitive Learning in Iontronic Memtransistors of 2D Molybdenum Disulfide <b>SAHA Puranjoy</b>